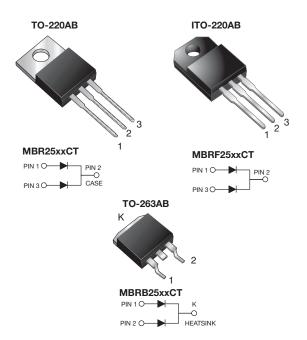
MBR25xxCT, MBRF25xxCT, MBRB25xxCT

Vishay General Semiconductor

Dual Common Cathode Schottky Rectifier



PRIMARY CHARACTERISTICS							
I _{F(AV)} 2 x 12.5 A							
V _{RRM}	V _{RRM} 35 V to 60 V						
I _{FSM}	150 A						
V _F 0.73 V at 30 A, 0.65 V at 15 A							
T _J max.	150 °C						
Package TO-220AB, ITO-220AB, TO-263AB							
Diode variations	Common cathode						

FEATURES

Power pack



- · Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- · High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB
Epoxy meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade
Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix

meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	MBR2535CT	MBR2545CT	MBR2550CT	MBR2560CT	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	35	45	50	60	
Working peak reverse voltage	Working peak reverse voltage		35	45	50	60	V
Maximum DC blocking voltage		V_{DC}	35	45	50	60	1
Maximum average forward rectified current	total device		25				
at T _C = 130 °C	per diode	I _{F(AV)}	12.5				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	150				
Peak repetitive reverse surge current per diode at $t_p = 2 \mu s$, 1 kHz		I _{RRM}	1.0 0.5		.5	- A	
Peak non-repetitive reverse energy (8/20 μs waveform) per diode		E _{RSM}	25				mJ
Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 k Ω		V _C	25				kV
Voltage rate of change (rated V _R)		dV/dt	10 000			V/µs	
Operating junction temperature range		TJ	-65 to +150			°C	
Storage temperature range		T _{STG}	-65 to +175]
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500			V	



MBR25xxCT, MBRF25xxCT, MBRB25xxCT

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	MBR2535CT	MBR2545CT	MBR2550CT	MBR2560CT	UNIT
Maximum instantaneous forward voltage per diode	I _E = 15 A	T _C = 25 °C	C V _F (1)	-		0.75		V
	IF = 13 A	T _C = 125 °C		-		0.65		
	I _F = 30 A	T _C = 25 °C		0.82		-		
	IF = 30 A	T _C = 125 °C		0.73		-		
Maximum instantaneous		T _C = 25 °C			0.2		1.0	
reverse current at blocking voltage per diode		T _C = 125 °C	I _R ⁽¹⁾	4	0	5	0	mA

Note

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER SYMBOL MBR MBRF MBRB UNIT						
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	1.5	4.5	1.5	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR2545CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2545CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB2545CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB2545CT-E3/81	1.35	81	800/reel	Tape and reel		
TO-220AB	MBR2545CT-E3/4W	1.85	4W	50/tube	Tube		
TO-220AB	MBR2545CTHE3/45 (1)	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2545CTHE3/45 (1)	1.99	45	50/tube	Tube		
TO-263AB	MBRB2545CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB2545CTHE3/81 (1)	1.35	81	800/reel	Tape and reel		

Note

⁽¹⁾ AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES (T_C = 25 °C unless otherwise noted)

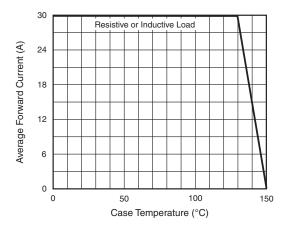


Fig. 1 - Forward Current Derating Curve

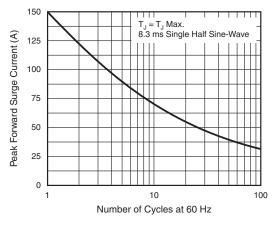


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

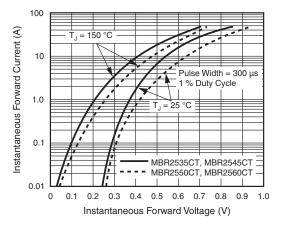


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

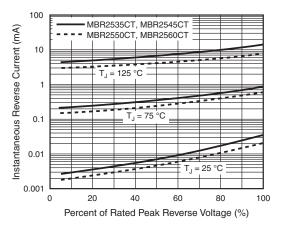


Fig. 4 - Typical Reverse Characteristics Per Diode

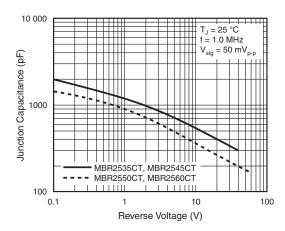


Fig. 5 - Typical Junction Capacitance Per Diode

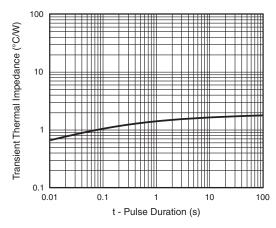


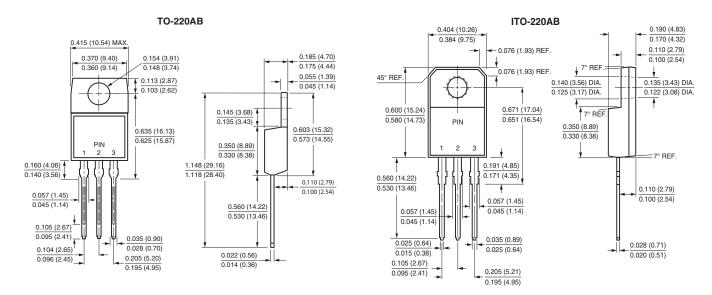
Fig. 6 - Typical Transient Thermal Impedance Per Diode

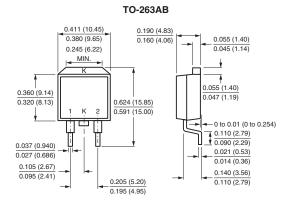


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





0.42 (10.66) MIN. 0.33 (8.38) MIN 0.591 (15.00) 0.08 (2.032) MIN. 0.105 (2.67)

0.095 (2.41)

Mounting Pad Layout



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